



Product Summary

V _{(BR)DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
60V	10mΩ @ V _{GS} = 10V	34A
	11.7m Ω @ V _{GS} = 4.5V	31.5A

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Backlighting
- **Power Management Functions**
- **DC-DC** Converters

60V N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI

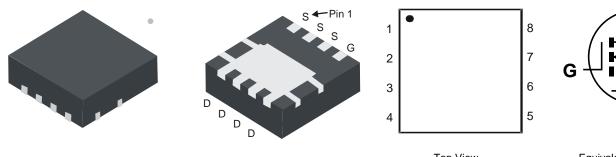
Features and Benefits

- Low RDS(ON) Ensures On-State Losses Are Minimized
- Excellent Q_{gd} x R_{DS(ON)} Product (FOM)
- Advanced Technology for DC-DC Converters
- Small Form Factor Thermally Efficient Package Enables Higher **Density End Products**
- 100% UIS (Avalanche) Rated
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: POWERDI®3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)

POWERDI3333-8



Top View

Bottom View

Top View Internal Schematic Equivalent Circuit

D

S

Ordering Information (Note 4)

Part Number	Case	Packaging
DMT6009LFG-7	POWERDI3333-8	2,000/Tape & Reel
DMT6009LFG-13	POWERDI3333-8	3,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. Notes:

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information



T69 = Product Type Marking Code YYWW = Date Code Marking YY = Last Digit of Year (ex: 15 = 2015) WW = Week Code (01 to 53)

Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	60	V	
Gate-Source Voltage	V _{GSS}	±16	V	
Continuous Drain Current (Note 5) V_{GS} = 10V	T _C = +25°C T _C = +70°C	ID	34 27	A
Continuous Drain Current (Note 5) V_{GS} = 10V	T _A = +25°C T _A = +70°C	ID	11 9	A
Maximum Continuous Body Diode Forward Current (Note 5)	IS	2.4	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	IDM	90	А	
Avalanche Current, L=0.1mH	I _{AS}	28.6	A	
Avalanche Energy, L=0.1mH	E _{AS}	40.8	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.08	W
Thermal Resistance, Junction to Ambient (Note 5)		R _{0JA}	60	°C/W
Total Power Dissipation (Note 5) $T_{C} = +25^{\circ}C$		PD	19.2	W
Thermal Resistance, Junction to Case (Note 5)		R _{ejc}	6.5	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Note: 5. ReJA is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate. ReJC is guaranteed by design while ReJA is determined by the user's board design.



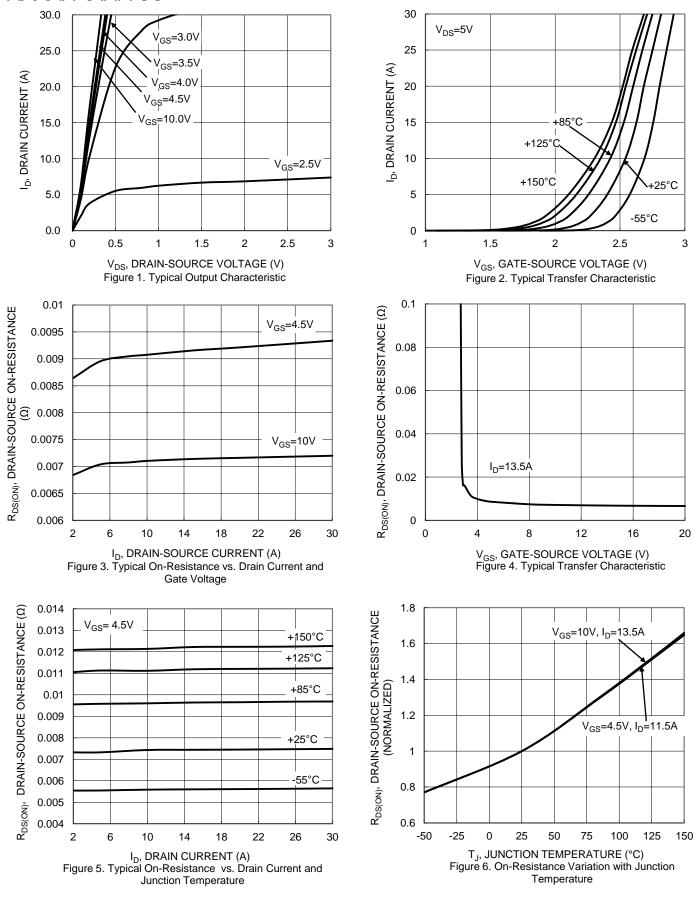
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

		1				
Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)						
BV _{DSS}	60	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
I _{DSS}	_	_	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$	
V _{GS(TH)}	0.7	—	2	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
	—	—	10	mΩ	V _{GS} = 10V, I _D = 13.5A	
KDS(ON)	_	—	11.7		V _{GS} = 4.5V, I _D = 11.5A	
V _{SD}	_	—	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
					·	
C _{iss}	_	1,925	-	pF	$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Coss	—	438	—			
C _{rss}	_	41	-			
Rq	_	1.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Qg	_	15.6	_			
Qg	_	33.5	—		V _{DS} = 30V, I _D = 13.5A	
Q _{gs}	_	4.7	_	nc		
Q _{gd}	_	5.3	_			
t _{D(ON)}	_	4.5	—		$V_{DD} = 30V, V_{GS} = 10V,$ $R_G = 6\Omega, I_D = 13.5A$	
t _R	_	8.6				
t _{D(OFF)}	—	35.9	—	ns		
t _F	_	15.7	—	1		
t _{RR}	_	18.2	—	ns		
Q _{RR}	_	33.1	—	nC	I _F = 13.5A, di/dt = 400A/μs	
	IDSS IGSS VGS(TH) RDS(ON) VSD Ciss Coss Crss Crss Rq Qg Qg Qg Qg tD(ON) tR tD(OFF) tF tF tRR	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	

6. Short duration pulse test used to minimize self-heating effect.7. Guaranteed by design. Not subject to product testing. Notes:



DMT6009LFG



DMT6009LFG Document number: DS37741 Rev. 2 - 2

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DMT6009LFG

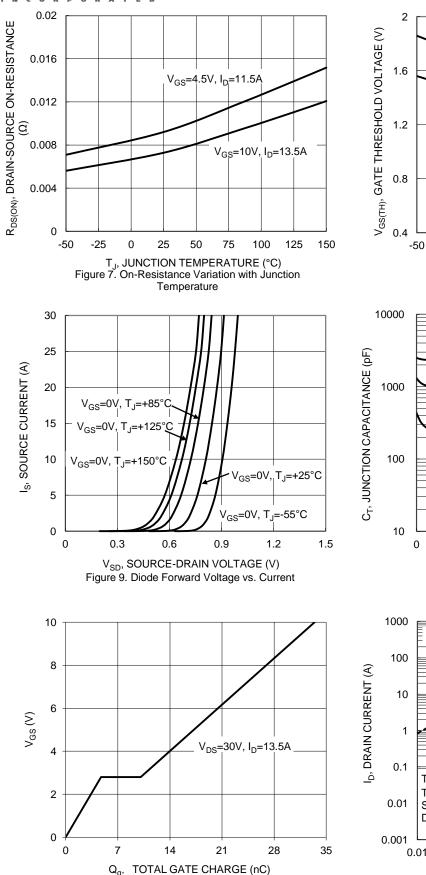
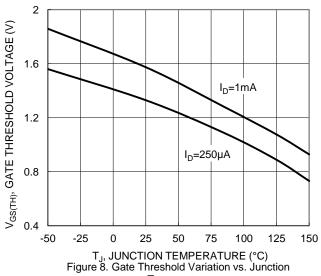
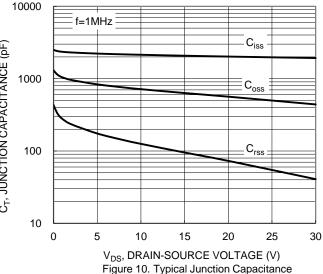
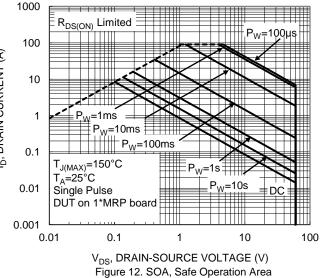


Figure 11. Gate Charge

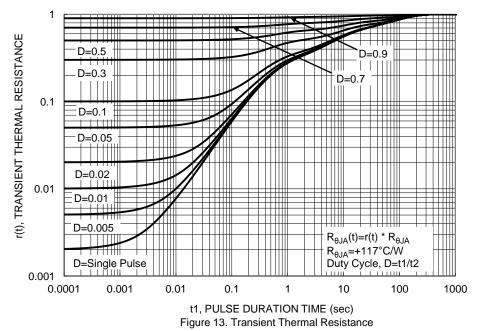








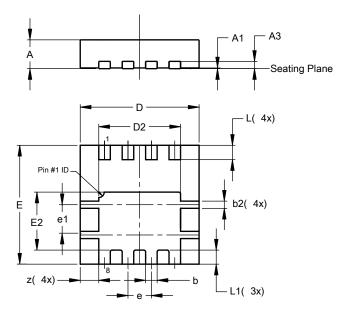






Package Outline Dimensions

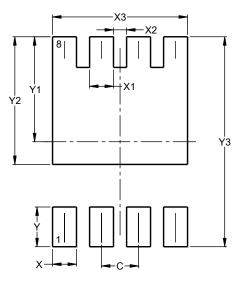
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



P	POWERDI3333-8						
Dim	Min	Max	Тур				
Α	0.75	0.85	0.80				
A1	0.00	0.05	0.02				
A3		-	0.203				
b	0.27	0.37	0.32				
b2	-	-	0.20				
D	3.25	3.35	3.30				
D2	2.22	2.32	2.27				
E	3.25	3.35	3.30				
E2	1.56	1.66	1.61				
е		-	0.65				
e1	0.79	0.89	0.84				
L	0.35	0.45	0.40				
L1	_	_	0.39				
z	_	-	0.515				
All I	All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



POWERDI3333-8

Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700

POWERDI3333-8



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